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10.	An accurate approach for analyzing inhomogeneous Schottky diodes with a Gaussian distribution of barrier heights. Subhash Chand Semiconductor Science & Technology 17 , (2002) L36-L40
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18.	Low Temperature Charge Transport Study in p-Toluenesulfonic Acid Doped Polyaniline Atul Kapil, Manish Taunk and Subhash Chand Asian Journal of Chemistry Vol. 21 , No. 10 (2009), S138-142 IF= 0.27
19.	Preparation and charge transport studies of chemically synthesized polyaniline Atul Kapil, Manish Taunk and Subhash Chand J Mater Sci: Mater. Electron. 21 , 399-404 (2010). IF= 1.486 ISSN: 0957-4522 (print version) ISSN: 1573-482X (electronic version)
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27.	Electrical characterization of Ni/n-ZnO/p-Si/Al heterostructure fabricated by pulsed laser deposition technique Journal of Alloys and Compounds 613 (2014) 395–400 Subhash Chand and Rajender Kumar ISSN: 0925-8388
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34.	Structural, Electrical and Red Emission Properties of Pd/n-ZnO/p-Si/Al Heterostructures Rajender Kumar and Subhash Chand Electron. Mater. Lett. 11 (973-981) 2015 DOI: 10.1007/s13391-015-4348-y 2014 Impact factor = 1.980 ISSN: 1738-8090 (print version) ISSN: 2093-6788 (electronic version)
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39.	Fabrication and electrical characterization of nickel/p-Si Schottky diode at low temperature Rajender Kumar, Subhash Chand Solid State Sciences 58 (2016) 115-121 10.1016/j.solidstatesciences.2016.06.003 Impact Factor: 2.041 5-Year Impact Factor: 1.916 ISSN 1293-2558

